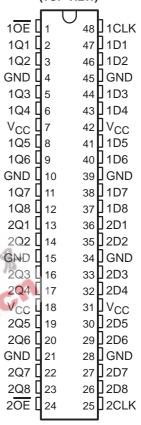
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- State-of-the-Art Advanced BiCMOS
 Technology (ABT) Widebus™ Design for
 2.5-V and 3.3-V Operation and Low Static
 Power Dissipation
- Support Mixed-Mode Signal Operation (5-V Input and Output Voltages With 2.3-V to 3.6-V V_{CC})
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC} = 3.3 V, T_A = 25°C
- High Drive (-24/24 mA at 2.5-V and -32/64 mA at 3.3-V V_{CC})
- Power Off Disables Outputs, Permitting Live Insertion
- High-Impedance State During Power Up and Power Down Prevents Driver Conflict
- Uses Bus Hold on Data Inputs in Place of External Pullup/Pulldown Resistors to Prevent the Bus From Floating
- Auto3-State Eliminates Bus Current Loading When Output Exceeds V_{CC} + 0.5 V
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model; and Exceeds 1000 V Using Charged-Device Model, Robotic Method
- Flow-Through Architecture Facilitates
 Printed Circuit Board Layout
- Distributed V_{CC} and GND Pin Configuration
 Minimizes High-Speed Switching Noise
- Package Options Include Plastic Shrink Small-Outline (DL), Thin Shrink Small-Outline (DGG), Thin Very Small-Outline (DGV) Packages, and 380-mil Fine-Pitch Ceramic Flat (WD) Package

SN54ALVTH16374 . . . WD PACKAGE SN74ALVTH16374 . . . DGG, DGV, OR DL PACKAGE (TOP VIEW)



description

The 'ALVTH16374 devices are 16-bit edge-triggered D-type flip-flops with 3-state outputs designed for 2.5-V or 3.3-V V_{CC} operation, but with the capability to provide a TTL interface to a 5-V system environment. These devices are particularly suitable for implementing buffer registers, I/O ports, bidirectional bus drivers, and working registers.

These devices can be used as two 8-bit flip-flops or one 16-bit flip-flop. On the positive transition of the clock (CLK), the flip-flops store the logic levels set up at the data (D) inputs.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Widebus is a trademark of Texas Instruments Incorporated.

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description (continued)

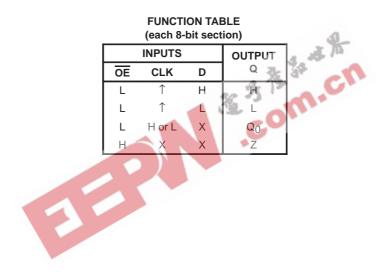
A buffered output-enable (\overline{OE}) input can be used to place the eight outputs in either a normal logic state (high or low logic levels) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and the increased drive provide the capability to drive bus lines without need for interface or pullup components.

OE does not affect internal operations of the flip-flop. Old data can be retained or new data can be entered while the outputs are in the high-impedance state.

Active bus-hold circuitry is provided to hold unused or floating data inputs at a valid logic level.

When V_{CC} is between 0 and 1.2 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 1.2 V, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

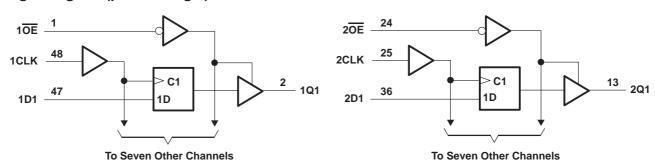
The SN54ALVTH16374 is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74ALVTH16374 is characterized for operation from –40°C to 85°C.





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logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	–0.5 V to 4.6 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high-impedance	
or power-off state, V _O (see Note 1)	0.5 V to 7 V
Voltage range applied to any output in the high state, V _O (see Note 1)	
Output current in the low state, Io: SN54ALVTH16374	96 mA
SN74ALVTH16374	128 mA
Output current in the high state, Io: SN54ALVTH16374	–48 mA
SN74ALVTH16374	–64 mA
Input clamp current, I _{IK} (V _I < 0)	–50 mA
Output clamp current, I_{OK} ($V_O < 0$)	
Package thermal impedance, θ_{JA} (see Note 2): DGG package	89°C/W
DGV package	93°C/W
DL package	94°C/W
Storage temperature range, T _{stg}	. −65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.

recommended operating conditions, V_{CC} = 2.5 V \pm 0.2 V (see Note 3)

			SN54	ALVTH1	6374	SN74ALVTH16374			UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		2.3		2.7	2.3		2.7	V
VIH	High-level input voltage	1.7			1.7			V	
V _{IL}	Low-level input voltage		4	0.7			0.7	V	
VI	Input voltage	0	Vcc	5.5	0	VCC	5.5	V	
ЮН	High-level output current			,0	-6			-8	mA
la.	Low-level output current			(0)	6			8	mA
lOL	Low-level output current; current duty cycle ≤ 50%; f ≥ 1 kHz		5	3	18			24	IIIA
Δt/Δν	Input transition rise or fall rate Outputs enabled		Q.		10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate					200			μs/V
TA	Operating free-air temperature				125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



^{2.} The package thermal impedance is calculated in accordance with JESD 51.

SN54ALVTH16374, SN74ALVTH16374 2.5-V/3.3-V 16-BIT EDGE-TRIGGERED D-TYPE FLIP-FLOPS WITH 3-STATE OUTPUTS SCES068F – JUNE 1996 – REVISED JANUARY 1999

recommended operating conditions, V_{CC} = 3.3 V \pm 0.3 V (see Note 3)

			SN54/	ALVTH1	6374	SN74	ALVTH1	6374	UNIT
			MIN	TYP	MAX	MIN	TYP	MAX	UNIT
Vcc	Supply voltage		3		3.6	3		3.6	V
VIH	High-level input voltage	2			2			V	
V _{IL}	Low-level input voltage		4	0.8			0.8	V	
VI	Input voltage	0	VCC	5.5	0	Vcc	5.5	V	
IOH	High-level output current			Q	-24			-32	mA
lai	Low-level output current			Ó	24			32	mA
lOL	Low-level output current; current duty cycle ≤	50%; f ≥ 1 kHz	\(\frac{1}{2}\)	2	48			64	IIIA
Δt/Δν	Input transition rise or fall rate	Outputs enabled	9		10			10	ns/V
Δt/ΔV _{CC}	Power-up ramp rate					200			μs/V
T _A	Operating free-air temperature				125	-40		85	°C

NOTE 3: All unused control inputs of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.



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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted)

PARAMETER		TEST CO	NDITIONS	SN54	ALVTH1	6374	SN74	ALVTH1	6374	UNIT
PA	KAMETER	1251 00	NDITIONS	MIN	TYP	MAX	MIN	TYP†	MAX	UNII
VIK		$V_{CC} = 2.3 \text{ V},$	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OH} = -100 μA	V _{CC} -0.	.2		V _{CC} -0	.2		
Vон		V _{CC} = 2.3 V	$I_{OH} = -6 \text{ mA}$	1.8						V
		VCC = 2.3 V	I _{OH} = -8 mA				1.8			
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V},$	I _{OL} = 100 μA			0.2			0.2	
			$I_{OL} = 6 \text{ mA}$			0.4				
VOL		V _{CC} = 2.3 V	$I_{OL} = 8 \text{ mA}$						0.4	V
		VCC = 2.3 V	I _{OL} = 18 mA			0.5				
			I _{OL} = 24 mA						0.5	
	Control inputs	$V_{CC} = 2.7 \text{ V},$	$V_I = V_{CC}$ or GND			±1			±1	
	Control inputs	V _{CC} = 0 or 2.7 V,	V _I = 5.5 V			<u>\$</u> 10			10	
Ц			V _I = 5.5 V		- 0/	10			10	μΑ
	Data inputs	$V_{CC} = 2.7 \text{ V}$	$V_I = V_{CC}$		3	1	1			
			V _I = 0	40		<u>–</u> 5			-5	
l _{off}		$V_{CC} = 0$,	V_I or $V_O = 0$ to $4.5 V_A$	19-	S &				±100	μΑ
I _{BHL} ‡		V _{CC} = 2.3 V,	V _I = 0.7 V	-	115			115		μΑ
I _{BHH} §		V _{CC} = 2.3 V,	V _I = 1.7 V	ON	-10			-10		μΑ
IBHLO	¶	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	300			300			μΑ
Івнно	#	$V_{CC} = 2.7 \text{ V},$	$V_I = 0$ to V_{CC}	-300			-300			μΑ
IEX		V _{CC} = 2.3 V,	V _O = 5.5 V			125			125	μΑ
I _{OZ(PL}	J/PD)☆	$V_{CC} \le 1.2 \text{ V}, V_{O} = 0.5 \text{ V}$ $V_{I} = \text{GND or } V_{CC}, \overline{OE} = 0.5 \text{ V}$	to V _{CC} , don't care			±100			±100	μΑ
lozh		V _{CC} = 2.7 V	$V_0 = 2.3 \text{ V},$ $V_1 = 0.7 \text{ V or } 1.7 \text{ V}$			5			5	μΑ
lozL		V _{CC} = 2.7 V	$V_O = 0.5 \text{ V},$ $V_I = 0.7 \text{ V or } 1.7 \text{ V}$			-5			-5	μА
		V _{CC} = 2.7 V,	Outputs high		0.04	0.1		0.04	0.1	
ICC		$I_0 = 0$,	Outputs low		2.3	4.5		2.3	4.5	mA
		$V_I = V_{CC}$ or GND	Outputs disabled		0.04	0.1		0.04	0.1	
Ci		V _{CC} = 2.5 V,	V _I = 2.5 V or 0		3.5			3.5		pF
Co		V _{CC} = 2.5 V,	V _O = 2.5 V or 0		6			6		pF

[†] All typical values are at V_{CC} = 2.5 V, T_A = 25°C.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

 $[\]P$ An external driver must source at least $I_{\mbox{\footnotesize{BHLO}}}$ to switch this node from low to high.

[#]An external driver must sink at least IBHHO to switch this node from high to low.

 $[\]parallel$ Current into an output in the high state when $V_O > V_{CC}$

^{*}High-impedance state during power up or power down

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electrical characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted)

D/	ARAMETER	TEST (CONDITIONS	SN54	ALVTH1	6374	SN74	ALVTH1	6374	UNIT
F#	AKAMETEK	1231	CONDITIONS	MIN	TYP [†]	MAX	MIN	TYP†	MAX	UNIT
٧ıK		V _{CC} = 3 V,	$I_{I} = -18 \text{ mA}$			-1.2			-1.2	V
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OH} = -100 μA	VCC-0	2		VCC-0	.2		
VOH		V _{CC} = 3 V	I _{OH} = -24 mA	2						V
		ACC = 2 A	$I_{OH} = -32 \text{ mA}$				2			
		$V_{CC} = 3 \text{ V to } 3.6 \text{ V},$	I _{OL} = 100 μA			0.2			0.2	
			I _{OL} = 16 mA						0.4	
VOL			I _{OL} = 24 mA			0.5				V
VOL		VCC = 3 V	I _{OL} = 32 mA						0.5	V
			I _{OL} = 48 mA			0.55				
			I _{OL} = 64 mA						0.55	
	Control innuts	V _{CC} = 3.6 V,	$V_I = V_{CC}$ or GND			<u>≯</u> ±1			±1	
	Control inputs	$V_{CC} = 0 \text{ or } 3.6 \text{ V},$	V _I = 5.5 V			10			10	
I			V _I = 5.5 V		23	10			10	μΑ
	Data inputs	V _{CC} = 3.6 V	$V_I = V_{CC}$	28.	4/3	1			1	
			V _I = 0	2 19	3	-5	-		-5	
l _{off}		$V_{CC} = 0$,	V_{I} or $V_{O} = 0$ to 4.5 V		M				±100	μΑ
I _{BHL} ‡		V _{CC} = 3 V,	V _I = 0.8 V	75			75			μΑ
I _{BHH} §		V _{CC} = 3 V,	V ₁ = 2 V	- 75			-75			μΑ
IBHLO		V _{CC} = 3.6 V,	$V_I = 0$ to V_{CC}	500			500			μΑ
IBHHC		V _{CC} = 3.6 V,	$V_I = 0$ to V_{CC}	-500			-500			μΑ
ΙΕΧ		V _{CC} = 3 V,	V _O = 5.5 V			125			125	μΑ
I _{OZ(Pl}	J/PD) [☆]	$V_{CC} \le 1.2 \text{ V}, V_{O} = \underline{0.5}$ V _I = GND or V _{CC} , OE	V to V _{CC} , = don't care			±100			±100	μΑ
lozh		V _{CC} = 3.6 V	V _O = 3 V,			5			5	μΑ
0211		00	V _I = 0.8 V or 2 V							
lozL		V _{CC} = 3.6 V	$V_0 = 0.5 V$,			-5			-5	μA
		00	V _I = 0.8 V or 2 V				ļ			<u> </u>
		$V_{CC} = 3.6 \text{ V},$	Outputs high	0.07 0.1				0.07	0.1	
ICC		$I_O = 0$, $V_I = V_{CC}$ or GND	Outputs low		3.2	5		3.2	5	mA
		Outputs disabled			0.07	0.1		0.07	0.1	
∆ICC□	1	$V_{CC} = 3 \text{ V to } 3.6 \text{ V, Or}$ Other inputs at V_{CC} or	ne input at V _{CC} – 0.6 V, GND			0.4			0.4	mA
Ci		V _{CC} = 3.3 V,	V _I = 3.3 V or 0		3.5			3.5		pF
Со		V _{CC} = 3.3 V,	V _O = 3.3 V or 0		6			6		pF

 $[\]uparrow$ All typical values are at V_{CC} = 3.3 V, T_A = 25°C.

[□]This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.



[‡] The bus-hold circuit can sink at least the minimum low sustaining current at V_{IL} max. I_{BHL} should be measured after lowering V_{IN} to GND and then raising it to V_{IL} max.

[§] The bus-hold circuit can source at least the minimum high sustaining current at V_{IH} min. I_{BHH} should be measured after raising V_{IN} to V_{CC} and then lowering it to V_{IH} min.

 $[\]P$ An external driver must source at least $I_{\mbox{\footnotesize{BHLO}}}$ to switch this node from low to high.

[#] An external driver must sink at least I_{BHHO} to switch this node from high to low.

Current into an output in the high state when VO > VCC

^{*}High-impedance state during power up or power down

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timing requirements over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

			SN54ALVT	H16374	SN74ALVT	H16374	UNIT	
			MIN	MAX	MIN	MAX	UNIT	
fclock	Clock frequency			150		150	MHz	
t _W	Pulse duration, CLK high or low		1.5	<i>S.</i>	1.5		ns	
	Catura time, data hafara Cl KA	Data high	1.1 0	E	1		no	
t _{su}	Setup time, data before CLK↑	Data low	1.4		1.3		ns	
4.	Hold time, data after CLK↑	Data high	0.6		0.5			
th	Holu tille, data alter OLIVI	0.9		0.8		ns		

timing requirements over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

				SN54ALVT	H16374	SN74ALVT	H16374	UNIT
				MIN	MAX	MIN	MAX	UNIT
fclock	Clock frequency			4	250		250	MHz
t _W	Pulse duration, CLK high or low		4	1.5	4.	1.5		ns
	Octor for data hafara OLKA		Data high	1.1		1		20
t _{su}	Setup time, data before CLK↑	Data low		1.6		1.5		ns
4.	Hold time, data after CLK↑		Data high	0.6		0.5		
^t h	noid time, data after CERT		Data low	2 1.1		1		ns

switching characteristics over recommended operating free-air temperature range, C_L = 30 pF, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

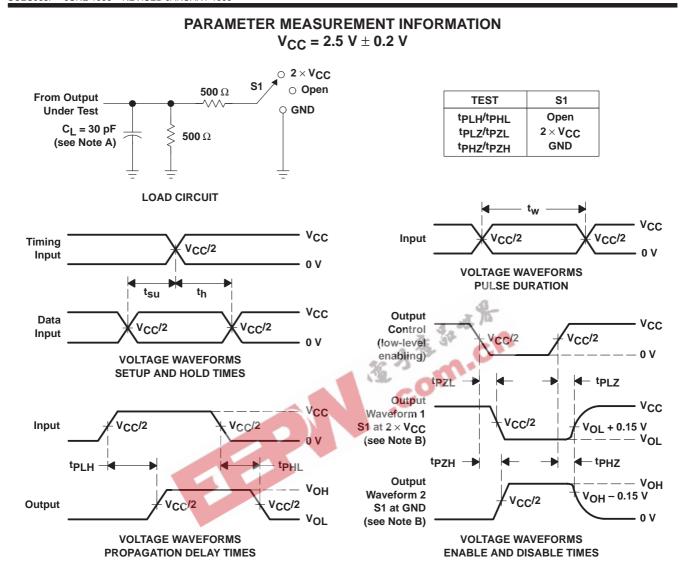
PARAMETER	FROM	ТО	SN54ALVTH16374	SN74ALVTH1637	4 UNIT
PARAMETER	(INPUT)	(OUTPUT)	MIN MAX	MIN MA	X UNII
f _{max}			150	150	MHz
t _{PLH}	CLK	Q	1.4 3.9	1.5	.8
t _{PHL}	CLK	<u> </u>	1.4 3.9	1.5	.8 ns
^t PZH	ŌĒ	Q	1, 4.2	1 4	.1 ns
t _{PZL}	OE .	ď	3.8	1 3	.7
^t PHZ	OE	Q	1.7 4.3	1.8 4	.2 ns
t _{PLZ}		ų ų	1 3.5	1 3	.4

switching characteristics over recommended operating free-air temperature range, C_L = 50 pF, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 2)

PARAMETER	FROM	то	SN54ALVT	H16374	SN74ALVT	UNIT	
PARAMETER	(INPUT) (OUTPUT)		MIN	MAX	MIN	MAX	UNIT
f _{max}			250	N.	250		MHz
t _{PLH}	CLK	0	1	3.4	1	3.2	nc
^t PHL	OLK	Q	1 0	3.3	1	3.2	ns
^t PZH	ŌĒ	Q	2	3.9	1	3.8	20
^t PZL	OE	ď	70	3.4	1	3.3	ns
t _{PHZ}	ŌĒ	Q	& 1	4.7	1	4.6	ns
t _{PLZ}	OE .		1	4.4	1	4.2	115



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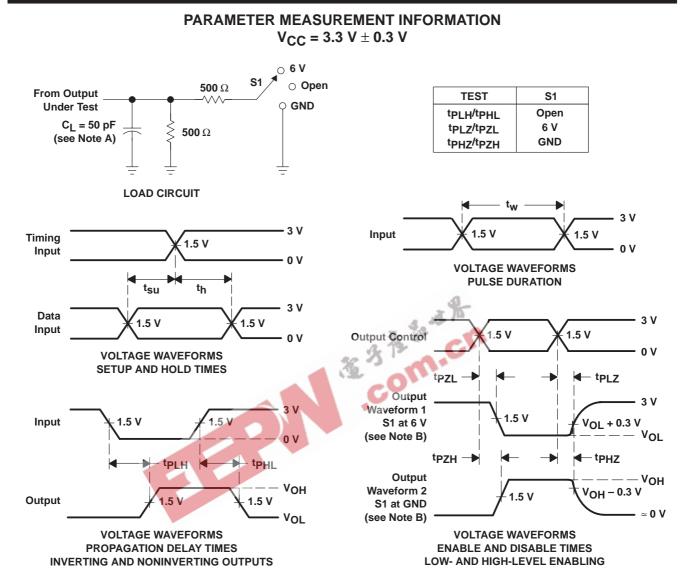


NOTES: A. C_I includes probe and jig capacitance.

- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_Q = 50 \ \Omega$, $t_f \leq$ 2 ns, $t_f \leq$ 2 ns.
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform22 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, $Z_O = 50 \,\Omega$, $t_f \leq$ 2.5 ns. $t_f \leq$ 2.5 ns.
 - D. The outputs are measured one at a time with one transition per measurement.

Figure 2. Load Circuit and Voltage Waveforms



PACKAGE OPTION ADDENDUM

4-Oct-2005

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan ⁽²⁾	Lead/Ball Finish	MSL Peak Temp ⁽³⁾
74ALVTH16374GRE4	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16374VRE4	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
74ALVTH16374ZQLR	ACTIVE	VFBGA	ZQL	56	1000	Green (RoHS & no Sb/Br)	SNAGCU	Level-1-260C-UNLIM
SN74ALVTH16374DL	ACTIVE	SSOP	DL	48	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16374DLR	ACTIVE	SSOP	DL	48	1000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16374GR	ACTIVE	TSSOP	DGG	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
SN74ALVTH16374KR	ACTIVE	VFBGA	GQL	56	1000	TBD	SNPB	Level-1-240C-UNLIM
SN74ALVTH16374VR	ACTIVE	TVSOP	DGV	48	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

⁽¹⁾ The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS) or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

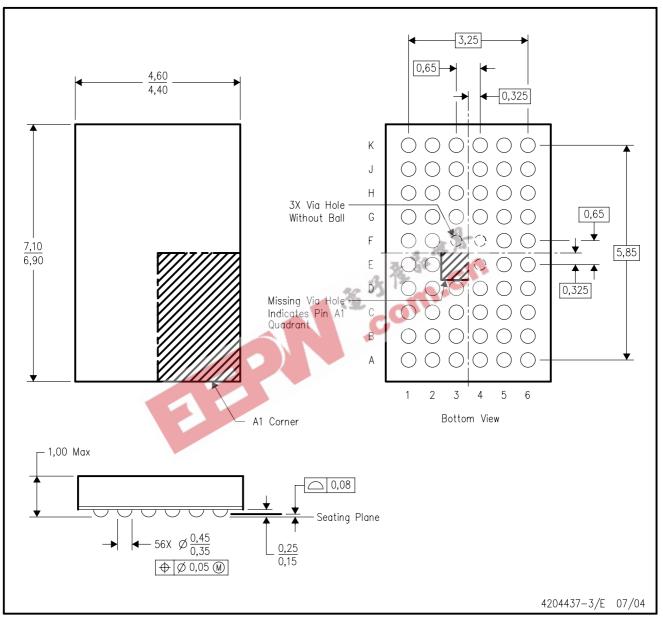
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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ZQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES:

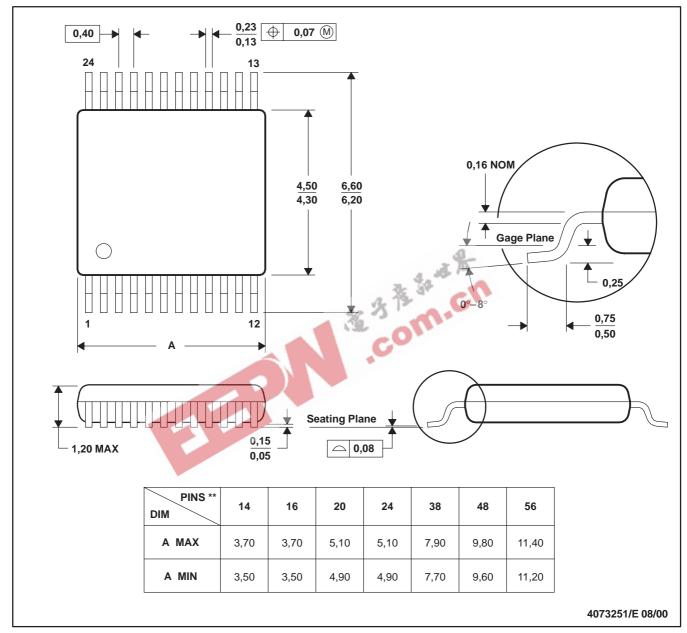
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is lead-free. Refer to the 56 GQL package (drawing 4200583) for tin-lead (SnPb).



DGV (R-PDSO-G**)

24 PINS SHOWN

PLASTIC SMALL-OUTLINE



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

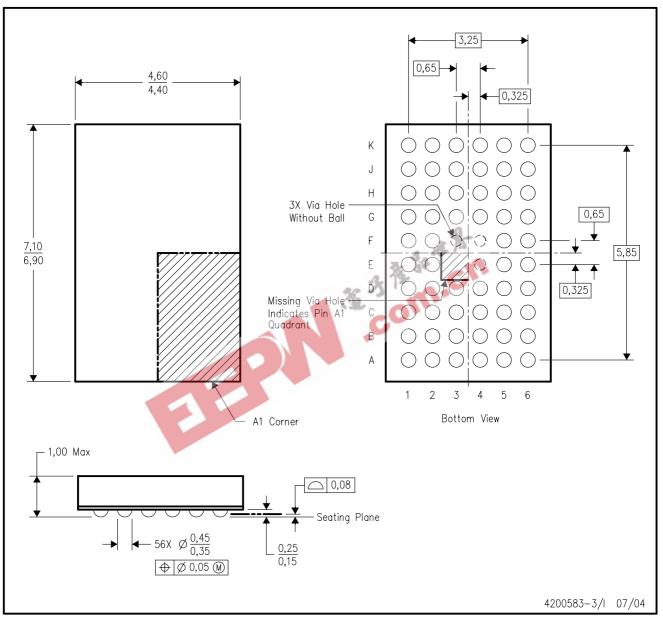
C. Body dimensions do not include mold flash or protrusion, not to exceed 0,15 per side.

D. Falls within JEDEC: 24/48 Pins – MO-153 14/16/20/56 Pins – MO-194



GQL (R-PBGA-N56)

PLASTIC BALL GRID ARRAY



NOTES:

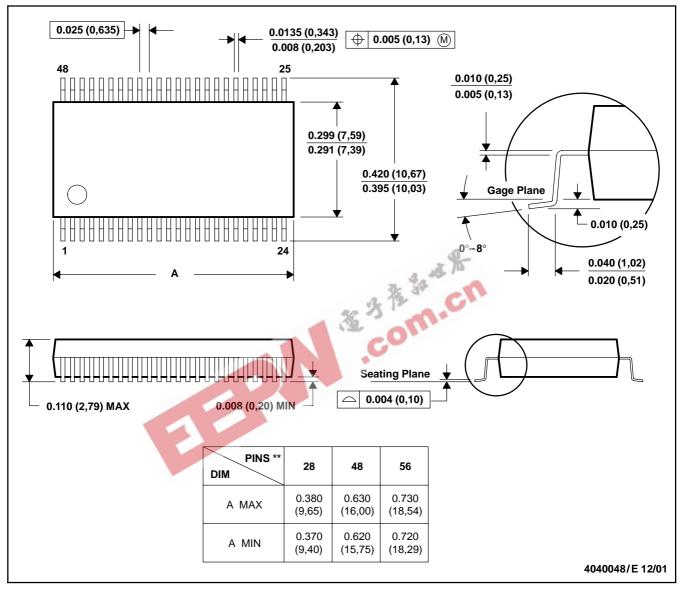
- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Falls within JEDEC MO-225 variation BA.
- D. This package is tin-lead (SnPb). Refer to the 56 ZQL package (drawing 4204437) for lead-free.



DL (R-PDSO-G**)

48 PINS SHOWN

PLASTIC SMALL-OUTLINE PACKAGE



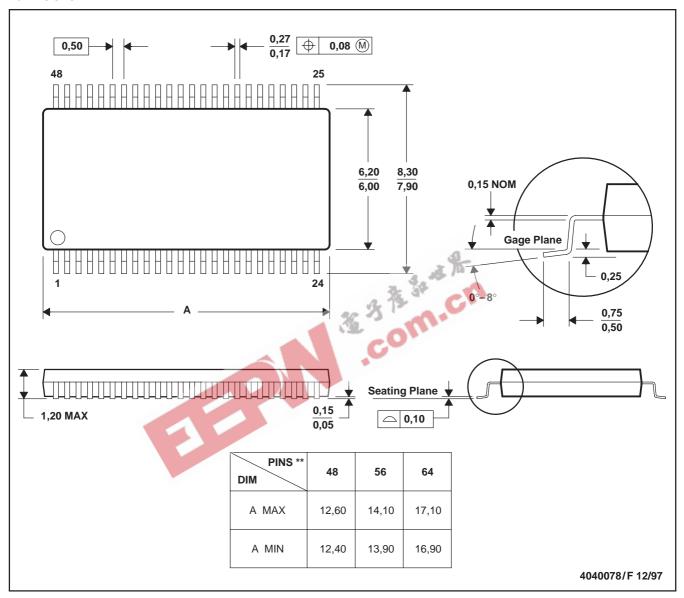
NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MO-118

DGG (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

48 PINS SHOWN



NOTES: A. All linear dimensions are in millimeters.

B. This drawing is subject to change without notice.

C. Body dimensions do not include mold protrusion not to exceed 0,15.

D. Falls within JEDEC MO-153

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